

C1210H183F1GACTU

Aliases (C1210H183F1GAC7800) SMD Indust COG HT200C, Ceramic, 0.018 uF, 1%, 100 VDC, COG, SMD, MLCC, High Temperature, Ultra-Stable, Low Loss, 1210, 1.5 mm



Click here for the 3D model.

Dimensions	
Chip Size	1210
L	3.2mm +/-0.2mm
W	2.5mm +/-0.2mm
т	0.78mm +/-0.10mm
S	1.5mm MIN
В	0.5mm +/-0.25mm

Plastic Tape

Packaging Specifications

Packaging	T&R, 180mm,
Packaging Quantity	4000

General Information	
Series	SMD Indust COG HT200C
Style	SMD Chip
Description	SMD, MLCC, High Temperature, Ultra-Stable, Low Loss
Features	High Temp, Ultra-Stable, Low Loss
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	30 mg
Shelf Life	78 Weeks
MSL	1

Specifications	
Capacitance	0.018 uF
Measurement Condition	1 kHz 1.0Vrms
Tolerance	1%
Voltage DC	100 VDC
Dielectric Withstanding Voltage	250 VDC
Temperature Range	-55/+200°C
Temp. Coefficient	COG
Capacitance Change with Reference to +25°C and 0 VDC Applied (TCC)	30 ppm/C, 1kHz 1.0Vrms
Dissipation Factor	0.1% 1 kHz 1.0Vrms
Aging Rate	0% Loss/Decade Hour
Insulation Resistance	55.5556 GOhms

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